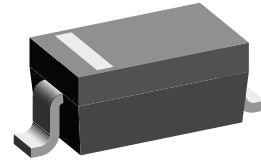


## Small Signal Fast Switching Diode

### Features

- These diodes are also available in other case styles including the DO35 case with the type designation 1N4148, the MiniMELF case with the type designation LL4148, and the SOT23 case with the type designation IMBD4148-V.
- Silicon epitaxial planar diode
- Fast switching diodes
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



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### Mechanical Data

**Case:** SOD123 plastic case

**Weight:** approx. 10.3 mg

#### Packaging Codes/Options:

GS18/10 k per 13" reel (8 mm tape), 10 k/box

GS08/3 k per 7" reel (8 mm tape), 15 k/box

### Parts Table

Part	Ordering code	Marking	Remarks
1N4148W-V	1N4148W-V-GS18 or 1N4148W-V-GS08	A2	Tape and Reel

### Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		$V_R$	75	V
Repetitive peak reverse voltage		$V_{RRM}$	100	V
Average rectified current half wave rectification with resistive load	$f \geq 50\text{ Hz}$	$I_{F(AV)}$	150 <sup>1)</sup>	mA
Surge forward current	$t < 1\text{ s}$ and $T_j = 25\text{ }^{\circ}\text{C}$	$I_{FSM}$	500	mA
Power dissipation		$P_{tot}$	350 <sup>1)</sup>	mW

Note:

<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature.

### Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		$R_{thJA}$	357 <sup>1)</sup>	K/W
Junction temperature		$T_j$	150	$^{\circ}\text{C}$
Storage temperature		$T_{stg}$	- 65 to + 150	$^{\circ}\text{C}$

Note:

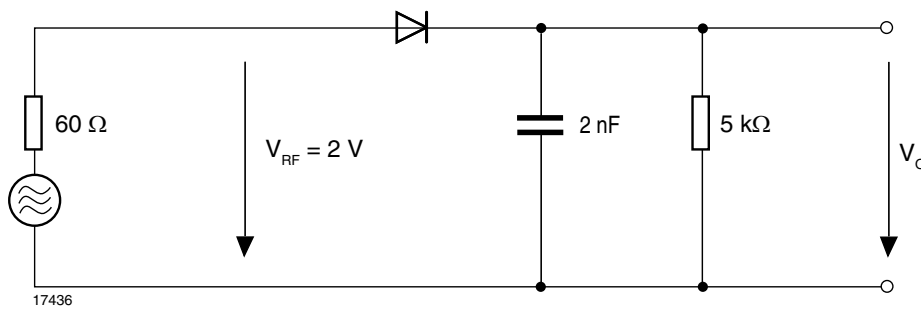
<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature.

## Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	$I_F = 10\text{ mA}$	$V_F$			1000	mV
	$I_F = 100\text{ mA}$	$V_F$			1200	mV
Leakage current	$V_R = 20\text{ V}$	$I_R$			25	nA
	$V_R = 75\text{ V}$	$I_R$			5	$\mu\text{A}$
	$V_R = 100\text{ V}$	$I_R$			100	$\mu\text{A}$
	$V_R = 20\text{ V}, T_J = 150\text{ }^{\circ}\text{C}$	$I_R$			50	$\mu\text{A}$
Diode capacitance	$V_F = V_R = 0\text{ V}$	$C_D$			4	pF
Voltage rise when switching ON (tested with 50 mA pulses)	tested with 50 mA pulses, $t_p = 0.1\text{ }\mu\text{s}$ , rise time < 30 ns, $f_p = (5\text{ to }100)\text{ kHz}$	$V_{fr}$			2.5	V
Reverse recovery time	$I_F = 10\text{ mA}, I_R = 1\text{ mA}, V_R = 6\text{ V},$ $R_L = 100\text{ }\Omega$	$t_{rr}$			4	ns
Rectification efficiency	$f = 100\text{ MHz}, V_{RF} = 2\text{ V}$	$\eta_v$	0.45			

## Rectification Efficiency Measurement Circuit



## Typical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

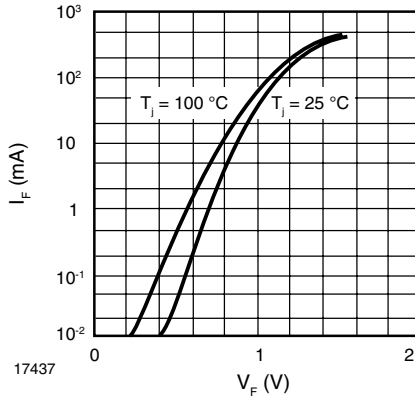


Figure 1. Forward characteristics

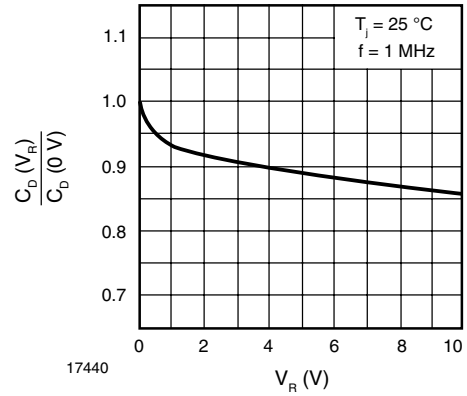


Figure 4. Relative Capacitance vs. Reverse Voltage

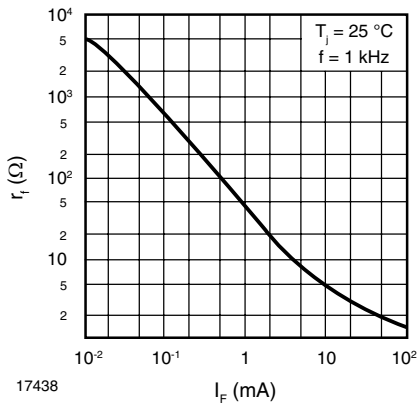


Figure 2. Dynamic Forward Resistance vs. Forward Current

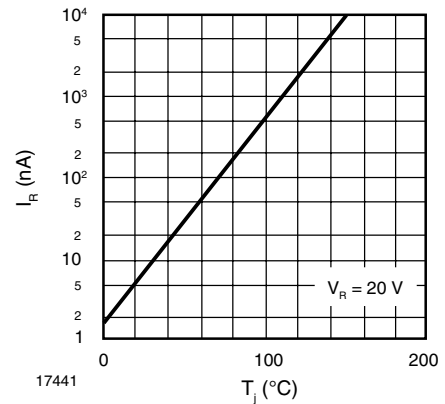


Figure 5. Leakage Current vs. Junction Temperature

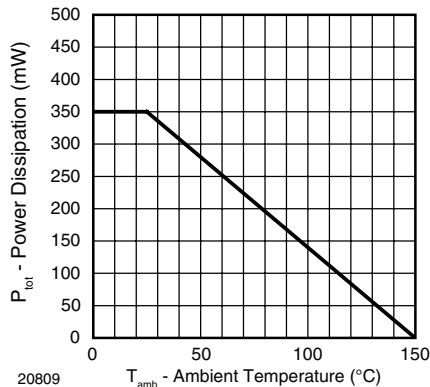


Figure 3. Admissible Power Dissipation vs. Ambient Temperature

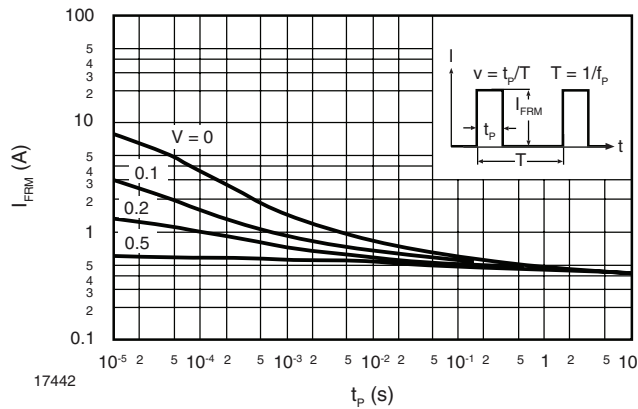
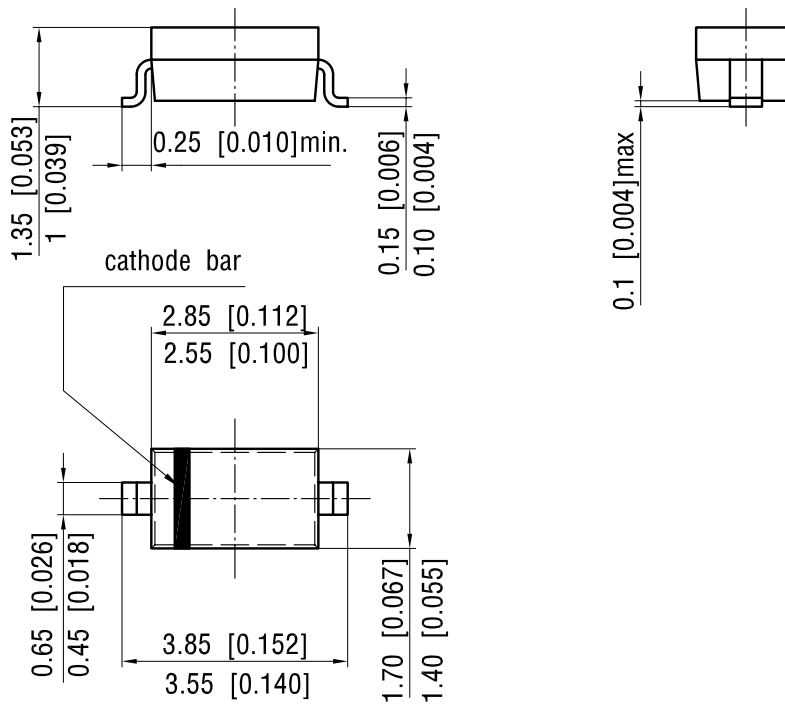
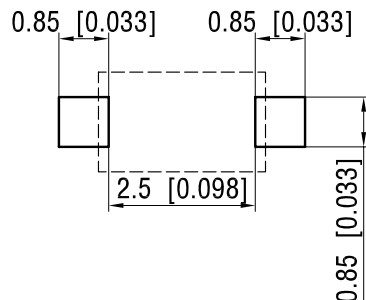


Figure 6. Admissible Repetitive Peak Forward Current vs. Pulse Duration

## Package Dimensions in millimeters (inches): SOD123



foot print recommendation:



Rev. 03 - Date: 08.November.2004  
 Document no.:S8-V-3910.01-001 (4)  
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## Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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